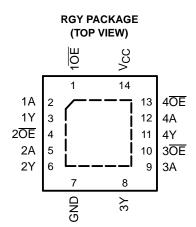
www.ti.com

SCES508A-NOVEMBER 2003-REVISED MARCH 2005

#### **FEATURES**

- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Sub-1-V Operable
- Max t<sub>pd</sub> of 2.1 ns at 1.8 V
- Low Power Consumption, 10-μA Max I<sub>CC</sub>
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1500-V Charged-Device Model (C101)



### **DESCRIPTION/ORDERING INFORMATION**

This quadruple bus buffer gate is designed for 0.8-V to 2.7-V  $V_{CC}$  operation, but is designed specifically for 1.6-V to 1.95-V  $V_{CC}$  operation.

The SN74AUC125 contains four independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable  $(\overline{OE})$  input is high.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKA	AGE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	QFN – RGY	Tape and reel	SN74AUC125RGYR	MS125

 Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLE**

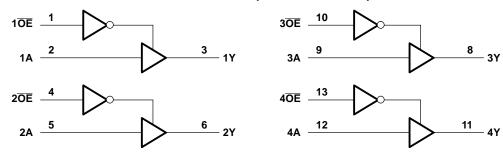
INPU	JTS	OUTPUT				
ŌĒ	Α	Y				
L	Н	Н				
L	L	L				
Н	Χ	Z				



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



## **LOGIC DIAGRAM (POSITIVE LOGIC)**



## Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage range		-0.5	3.6	V	
VI	Input voltage range <sup>(2)</sup>		-0.5	3.6	V	
Vo	Voltage range applied to any output in the hi	Voltage range applied to any output in the high-impedance or power-off state (2)				
Vo	Output voltage range <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA	
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA	
Io	Continuous output current			±20	mA	
	Continuous current through V <sub>CC</sub> or GND		±100	mA		
$\theta_{JA}$	Package thermal impedance <sup>(3)</sup>		47	°C/W		
T <sub>stg</sub>	Storage temperature range		-65	150	°C	

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The package thermal impedance is calculated in accordance with JESD 51-5.



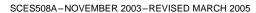
## SN74AUC125 QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS

## **Recommended Operating Conditions**(1)

			MIN	MAX	UNIT	
$V_{CC}$	Supply voltage		0.8	2.7	V	
		V <sub>CC</sub> = 0.8 V	V <sub>CC</sub>			
$V_{IH}$	High-level input voltage	V <sub>CC</sub> = 1.1 V to 1.95 V	0.65 × V <sub>CC</sub>		V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7			
		V <sub>CC</sub> = 0.8 V		0		
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 1.1 V to 1.95 V		0.35 × V <sub>CC</sub>	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7		
VI	Input voltage		0	3.6	V	
\/	Output valtage	Active state	0	$V_{CC}$	V	
Vo	Output voltage	3-state	0	3.6	V	
		V <sub>CC</sub> = 0.8 V		-0.7		
		V <sub>CC</sub> = 1.1 V		-3		
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 1.4 V		<b>-</b> 5	mA	
		V <sub>CC</sub> = 1.65 V		-8		
		$V_{CC} = 2.3 \text{ V}$		<b>-</b> 9		
		V <sub>CC</sub> = 0.8 V		0.7		
		V <sub>CC</sub> = 1.1 V		3		
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 1.4 V		5	mA	
		V <sub>CC</sub> = 1.65 V		8		
		$V_{CC} = 2.3 \text{ V}$		9		
Δt/Δν	Input transition rise or fall rate			20	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

<sup>(1)</sup> All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## SN74AUC125 QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS





### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		V <sub>cc</sub>	MIN	TYP <sup>(1)</sup> MA	UNIT
	I <sub>OH</sub> = -100 μA		0.8 V to 2.7 V	V <sub>CC</sub> - 0.1		
	$I_{OH} = -0.7 \text{ mA}$		0.8 V		0.55	
V	$I_{OH} = -3 \text{ mA}$		1.1 V	0.8		V
V <sub>OH</sub>	$I_{OH} = -5 \text{ mA}$		1.4 V	1		V
	$I_{OH} = -8 \text{ mA}$		1.65 V	1.2		
	$I_{OH} = -9 \text{ mA}$		2.3 V	1.8		
	$I_{OL} = 100 \mu A$		0.8 V to 2.7 V		0.	2
	$I_{OL} = 0.7 \text{ mA}$		0.8 V		0.25	
V	I <sub>OL</sub> = 3 mA		1.1 V		0.	3 V
V <sub>OL</sub>	I <sub>OL</sub> = 5 mA		1.4 V		0.	
	I <sub>OL</sub> = 8 mA		1.65 V		0.4	5
	I <sub>OL</sub> = 9 mA		2.3 V		0.	3
I <sub>I</sub>	$V_I = V_{CC}$ or GND		0 to 2.7 V		±	5 μΑ
I <sub>off</sub>	$V_I$ or $V_O = 2.7 \text{ V}$		0		±1	μΑ
l <sub>OZ</sub>	$V_O = V_{CC}$ or GND		2.7 V		±1	) μΑ
I <sub>cc</sub>	$V_I = V_{CC}$ or GND,	I <sub>O</sub> = 0	0.8 V to 2.7 V		1	μΑ
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND		2.5 V		2.5	pF
C <sub>o</sub>	$V_O = V_{CC}$ or GND		2.5 V		5	pF

<sup>(1)</sup> All typical values are at  $T_A = 25$ °C.

## **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L$  = 15 pF (unless otherwise noted) (see Figure 1)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = ± 0.		V <sub>CC</sub> = ± 0.			<sub>CC</sub> = 1.8 ± 0.15 \		V <sub>CC</sub> = ± 0.		UNIT
		(INPUT)	(001201)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
	t <sub>pd</sub>	Α	Υ	5.8	0.7	3.7	0.6	2.6	0.5	1	2.1	0.5	1.3	ns
	t <sub>en</sub>	ŌĒ	Y	7.5	0.9	4.1	0.7	2.9	0.6	1	2.2	0.6	1.4	ns
	t <sub>dis</sub>	ŌĒ	Y	6.4	1.6	5.1	1.5	3.6	1.4	2.4	3.5	1	2.6	ns

## **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 30 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>C</sub>	<sub>C</sub> = 1.8 \ : 0.15 V	/	V <sub>CC</sub> = : ± 0.2	UNIT	
	(INFOT)	(001F01)	MIN	TYP	MAX	MIN	MAX	
t <sub>pd</sub>	A	Υ	0.5	1.8	2.6	0.5	2.1	ns
t <sub>en</sub>	ŌĒ	Y	0.6	1.6	2.8	0.6	2.3	ns
t <sub>dis</sub>	ŌĒ	Υ	1.2	2.4	3.4	0.8	2.3	ns





SCES508A-NOVEMBER 2003-REVISED MARCH 2005

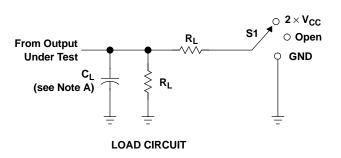
## **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 0.8 V TYP	V <sub>CC</sub> = 1.2 V TYP	V <sub>CC</sub> = 1.5 V TYP	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	UNIT
	Power	Outputs enabled	f 40 MHz	15	15	15	16	17	~F
C <sub>pd</sub>	dissipation capacitance	Outputs disabled	f = 10 MHz	2	2	2	3	4	pF

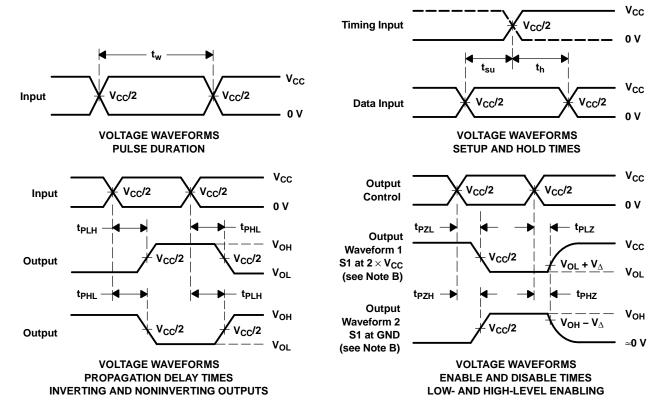


### PARAMETER MEASUREMENT INFORMATION



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	$2 \times V_{CC}$
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

V <sub>CC</sub>	CL	R <sub>L</sub>	$oldsymbol{V}_\Delta$
0.8 V	15 pF	<b>2 k</b> Ω	0.1 V
1.2 V $\pm$ 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.5 V ± 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.8 V ± 0.15 V	15 pF	<b>2 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	15 pF	<b>2 k</b> Ω	0.15 V
1.8 V $\pm$ 0.15 V	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	30 pF	500 Ω	0.15 V



- NOTES: A. C<sub>I</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{O}$  = 50  $\Omega$ , slew rate  $\geq$  1 V/ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



## PACKAGE OPTION ADDENDUM

10-Dec-2020

#### PACKAGING INFORMATION

www.ti.com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AUC125RGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MS125	Samples
SN74AUC125RGYRG4	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MS125	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





10-Dec-2020

## PACKAGE MATERIALS INFORMATION

www.ti.com 6-Nov-2020

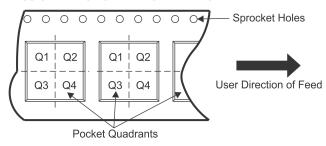
## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

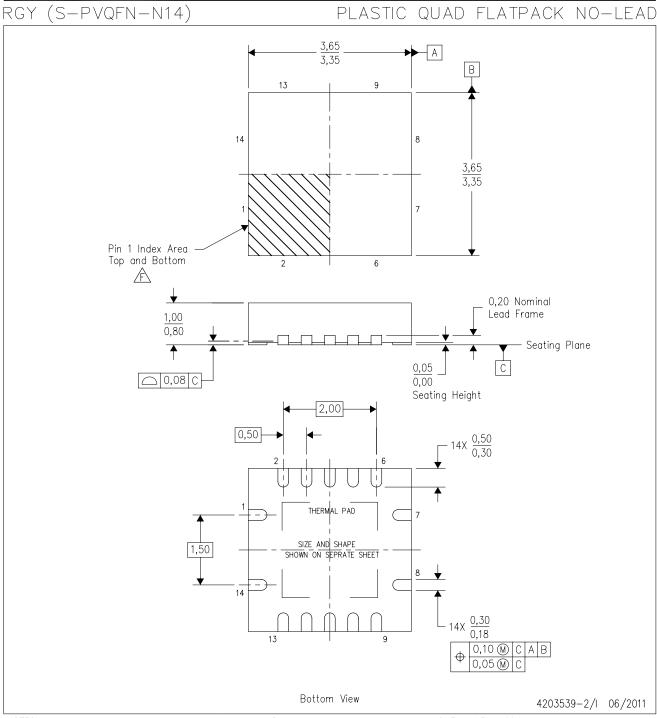
Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUC125RGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1

www.ti.com 6-Nov-2020



#### \*All dimensions are nominal

Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74AUC125RGYR	VQFN	RGY	14	3000	853.0	449.0	35.0	



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



## RGY (S-PVQFN-N14)

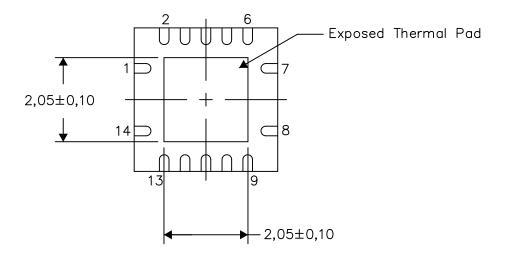
### PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

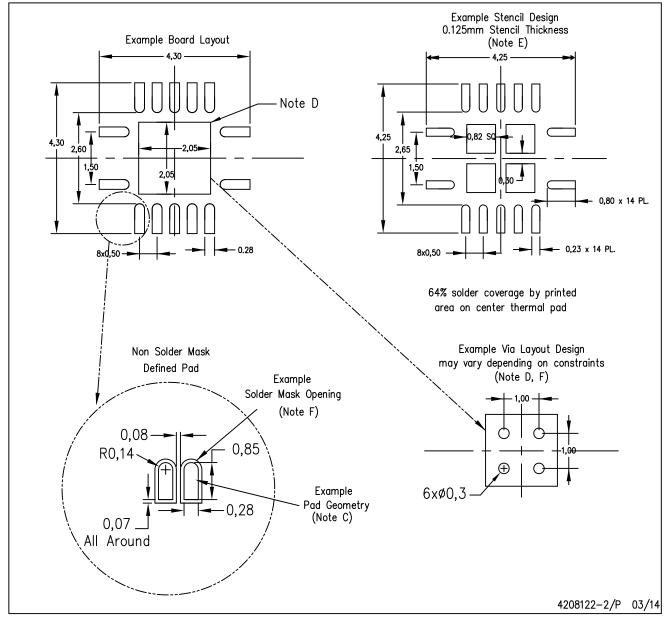
4206353-2/P 03/14

NOTE: All linear dimensions are in millimeters



# RGY (S-PVQFN-N14)

## PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="https://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

Tl's products are provided subject to Tl's Terms of Sale (<a href="www.ti.com/legal/termsofsale.html">www.ti.com/legal/termsofsale.html</a>) or other applicable terms available either on ti.com or provided in conjunction with such Tl products. Tl's provision of these resources does not expand or otherwise alter Tl's applicable warranties or warranty disclaimers for Tl products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2020, Texas Instruments Incorporated